

CGB4B3JB1E105M055AB

TDK Item Description : CGB4B3JB1E105MT****



Application & Main Feature

Commercial Grade (Low Profile)

Series

CGB4(2012) [EIA CC0805]



Dimensions

L 2.00mm +/-0.2mm
 W 1.25mm +/-0.2mm
 T 0.55mm Max.
 B 0.20mm Min.
 G 0.50mm Min.

Temperature Characteristic

JB (-25 to 85 degC +/-10%)

Rated Voltage

1E (25Vdc)

Capacitance

1uF

Capacitance Tolerance

M (+/-20%)

Dissipation Factor

7.5% Max.

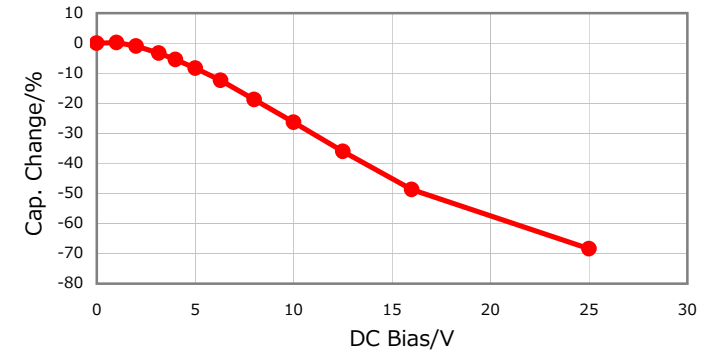
Insulation Resistance

500Mohm Min.

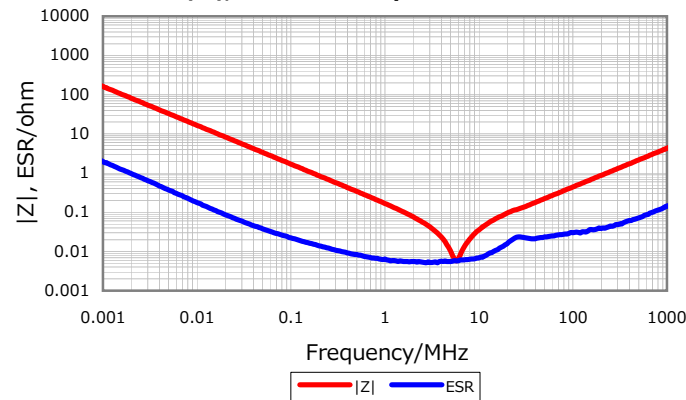
AEC-Q200

Not Applicable

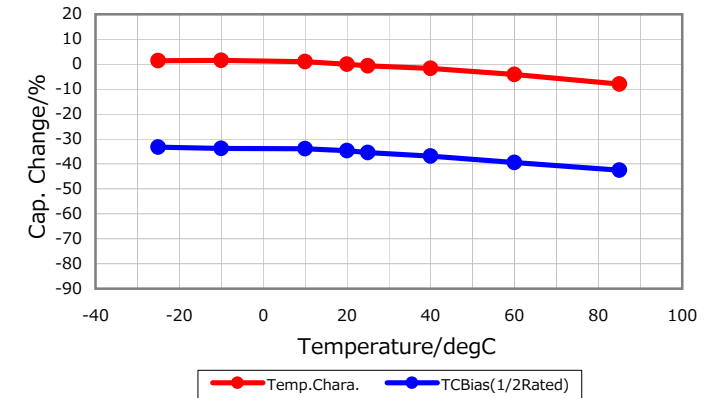
DC Bias Characteristic



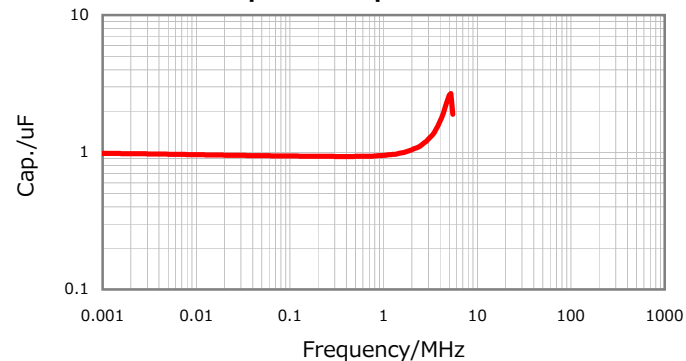
|Z|, ESR vs. Freq. Characteristics



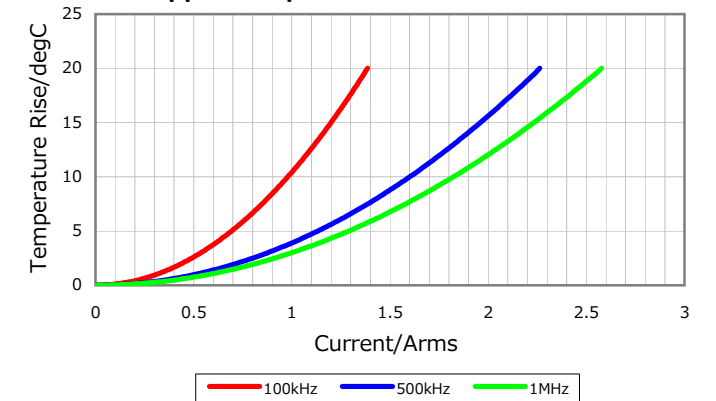
Temperature Characteristics



Cap. vs. Freq. Characteristic



Ripple Temperature Rise Characteristics



Characterization Sheet (Multilayer Ceramic Chip Capacitors)



All specifications are subject to change without notice.

January 4, 2016